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Joel D. Cox *et al.*

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Nonlocal and cascaded effects in nonlinear graphene nanoplasmonics†

Theis P. Rasmussen, ^a A. Rodríguez Echarri, ^b F. Javier García de Abajo ^{b,c} and Joel D. Cox ^{*a,d}

The ability of plasmons to focus light on nanometer length scales opens a wide range of enticing applications in optics and photonics, among which the enhancement of nonlinear light–matter interactions for all-optical modulation and spectral diversification emerges as a prominent theme. However, the sub-wavelength plasmonic near-field enhancement in good plasmonic materials such as noble metals is hindered by large ohmic losses, while conventional phase-matching of fields in bulk nonlinear crystals is not suitable for realizing nonlinear optical phenomena on the nanoscale. In contrast, anharmonic electron motion of free charge carriers in highly-doped graphene, which supports long-lived, highly-confined, and actively-tunable plasmons, renders the carbon monolayer an excellent platform for both plasmonics and nonlinear optics. Here we theoretically explore the enhancement in nonlinear response that can be achieved by interfacing multiple graphene nanostructures in close proximity to trigger nonlocal effects associated with large gradients in the electromagnetic near field. Focusing on second- and third-harmonic generation, we introduce a semianalytical formalism to describe interacting graphene nanoribbons with independent width, location, and electrical doping, so as to realize configurations in which plasmonic resonances may simultaneously enhance both the fundamental optical excitation frequency and harmonic intermediary and/or output frequencies. Our findings reveal the importance of both passive and active tuning in the design of atomically-thin nanostructures for nonlinear optical applications, and in particular emphasize the role played by nonlocal effects in generating an even-ordered nonlinear response that may contribute to other nonlinear optical processes through a cascaded interaction. We anticipate that our findings can aid in the design of actively-tunable nonlinear plasmonic resonators and metasurfaces.

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1 Introduction

Current research in nonlinear plasmonics seeks to intensify nonlinear optical phenomena on the nanoscale by exploiting the extreme light-focusing ability of plasmons—the collective oscillations of free charge carriers.^{1–4} The manipulation of light on nanometer length scales enabled by plasmonics,^{5,6} in tandem with spectral and temporal control of light by light through nonlinear optics,⁷ paves way for full spatio-temporal control over electromagnetic fields, with appealing prospects to

develop all-optical integrated devices.^{8–10} However, in practice, the subwavelength optical excitations supported by noble metals—the traditional material platform for plasmonics—are impeded by high ohmic losses that limit the achievable near-field enhancement sought in nonlinear optics applications.^{11,12} Furthermore, being defined by the intrinsic electronic properties of the host media and its geometry, plasmon resonances at near-infrared and visible frequencies in noble metals offer limited opportunities to achieve active tunability.^{13,14}

Graphene—the atomically-thin carbon monolayer—is now recognized as a platform for nano-optics at terahertz (THz) and infrared (IR) frequencies that supports high-quality plasmon resonances when doped with additional charge carriers.^{15,16} The emergence of highly-doped graphene in plasmonics has been further catalyzed by the electrical tunability of its plasmons, which exhibit stronger optical confinement than their noble metal counterparts, thus stimulating explorations across all areas of nanophotonics that capitalize on long-lived, strongly confined, and actively tunable optical resonances spanning the THz and near-IR spectral regimes.^{17–20} Within nonlinear plasmonics, graphene is rendered a particularly attractive

^aPOLIMA—Center for Polariton-driven Light–Matter Interactions, University of Southern Denmark, Campusvej 55, DK-5230 Odense M, Denmark.
E-mail: cox@mci.sdu.dk

^bICFO-Institut de Ciències Fotoniques, The Barcelona Institute of Science and Technology, 08860 Castelldefels, Barcelona, Spain

^cICREA-Institució Catalana de Recerca i Estudis Avançats, Passeig Lluís Companys 23, 08010 Barcelona, Spain

^dDanish Institute for Advanced Study, University of Southern Denmark, Campusvej 55, DK-5230 Odense M, Denmark

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material platform by its linear electronic dispersion relation at low energies that results in electron motion deviating significantly from the harmonic oscillation of an external electromagnetic field.^{21,22} The electron dispersion of graphene is thus deemed anharmonic, and gives rise to a strong intrinsic optical nonlinearity associated with harmonic generation that can be further amplified by graphene plasmons.^{23,24}

The nonlinear optical properties of extended graphene have been widely studied in experiment,^{25–29} where in some cases plasmon-assisted nonlinear optical phenomena have been observed.^{30–33} In parallel, theoretical proposals to develop nonlinear metasurfaces comprised of arrays of graphene nanostructures predict dramatic enhancements in the nonlinear yield due to localized plasmon resonances.^{34–36} Typically, such nonlinear metasurfaces are comprised of identical units arranged periodically on length scales comparable to the impinging light wavelength, so that the morphology and intrinsic optical properties of each isolated graphene nanostructure determine the optical response. However, two-dimensional (2D) materials such as graphene offer intriguing possibilities to develop heterostructures that combine nanoscale elements with complementary optical properties to interact on truly nanometer (*i.e.*, ≈ 1 nm) length scales,³⁷ leading to functionalities exceeding the sum of their individual components.^{38,39} In the case of graphene, such heterostructures offer additional promise due to the possibility of independently and electrically tuning the optical properties of different components,⁴⁰ which has yet to be explored in the context of nonlinear plasmonics.

Here, we theoretically investigate the plasmon-driven nonlinear optical response associated with second- and third-harmonic generation in actively-tunable graphene nanoribbon heterostructures. Our explorations emphasize the effect of spatial inhomogeneity on the plasmonic near fields produced by closely-spaced graphene nanoribbons, which can trigger even-ordered nonlinear optical processes in otherwise inversion-symmetric nanostructures.^{29,41,42} We base our work on a theoretical formalism that we introduce to facilitate a broad parametric sweep of the geometrical and intrinsic electrical properties of graphene nanoribbon ensembles to reveal the enhancement in harmonic generation that can be achieved by independent active and/or passive tuning of individual structures. We furthermore elucidate the role of cascaded nonlinear optical effects in graphene heterostructures, whereby third-harmonic generation is influenced by the second-order mixing of the fundamental field and its second harmonic. We anticipate that our findings can aid in the design of polariton-driven nonlinear optical processes in two-dimensional heterostructures.

2 Theory

We investigate graphene nanoribbon ensembles driven by monochromatic plane wave illumination, where parallel ribbons of varying size and doping can be arranged to tailor the plasmon-enhanced near fields that trigger a nonlinear

optical response, which we quantify by the net induced dipole moment of the ensemble that radiates into the far field. In what follows, we first outline the theoretical methods employed to describe both the linear and nonlinear optical response of arbitrary interacting 2D nanostructures in the quasistatic approximation, which is applied here to one-dimensional nanoribbons but can be straightforwardly adapted to treat other 2D geometries. We then provide expressions governing the intrinsic nonlocal nonlinear optical response of free electrons in graphene.

2.1 Optical response of two-dimensional nanostructure ensembles

We theoretically explore the interaction of N distinct 2D nanostructures with light characterized by a uniform electric field $\mathbf{E}^{\text{ext}}e^{-i\omega t} + \text{c.c.}$, where the amplitude \mathbf{E}^{ext} is assumed to be real and linearly polarized. When the nanostructures are all contained within a region of size well-below the wavelength of light that excites them, the optical response can be described in the quasistatic approximation by the scalar potential

$$\Phi(\mathbf{r}, t) = \Phi^{\text{ext}}(\mathbf{r}, t) + \sum_{j=1}^N \int d^3\mathbf{r}' \frac{\rho_j(\mathbf{R}', t)}{|\mathbf{r} - \mathbf{r}'|} \delta(z' - z_j), \quad (1)$$

where Φ^{ext} denotes the external potential associated with \mathbf{E}^{ext} and ρ_j is the induced 2D charge density in structure j that lies on the plane $\mathbf{r} = (\mathbf{R}, z_j)$ spanning coordinates $\mathbf{R} = (x, y)$. It is convenient to decompose the total potential in a perturbation series with the external field amplitude as a perturbation parameter according to

$$\Phi(\mathbf{r}, t) = \sum_{n=1}^{\infty} \sum_{s=n}^n \Phi^{(n,s)}(\mathbf{r}) e^{-is\omega t}, \quad (2)$$

where n indicates the perturbation order in \mathbf{E}^{ext} and s the harmonic index, such that $|s| \leq n$ with $n \geq 1$. Now, at order n and harmonic s , the induced charge in structure j satisfies the continuity equation $\rho_j^{(n,s)} = -(i/s\omega)\nabla_{\mathbf{R}} \cdot \mathbf{j}_j^{(n,s)}$ for the associated (surface) current density

$$\mathbf{j}_j^{(n,s)}(\mathbf{R}) = f_j(\mathbf{R})\sigma_j^{(1,s)}\mathbf{E}_j^{(n,s)}(\mathbf{R}) + \mathbf{j}_{j,\text{NL}}^{(n,s)}(\mathbf{R}), \quad (3)$$

where the first term accounts for the linear response to the field $\mathbf{E}_j^{(n,s)}(\mathbf{R}) = -\nabla_{\mathbf{R}}\Phi^{(n,s)}(\mathbf{R}, z_j)$ within the 2D structure, mediated by a filling function $f_j(\mathbf{R})$ that captures the spatial dependence of the intrinsic linear conductivity $\sigma_j^{(1,s)}$ (*i.e.*, $f_j = 1$ for points in the structure and 0 otherwise), and the second term describes contributions from the intrinsic (*i.e.*, bulk) nonlinear response of graphene.

To linear order, we take $n = s = 1$ in eqn (3) and recover Ohm's law $\mathbf{j}_j^{(1,1)} = f_j\sigma_j^{(1,1)}\mathbf{E}_j^{(1,1)}$, from which the charge density can be expressed in terms of the potential as

$$\rho_j^{(1,1)}(\mathbf{R}) = \frac{i}{\omega}\sigma_j^{(1,1)}\nabla_{\mathbf{R}} \cdot [f_j(\mathbf{R})\nabla_{\mathbf{R}}\Phi^{(1,1)}(\mathbf{R}, z_j)]. \quad (4)$$

We then introduce a normalized coordinate $\vec{\theta}$ that parametrizes a 2D structure, such that $f_j(\mathbf{R}_j + W_j\vec{\theta}) = 1$ within struc-

ture j and vanishes elsewhere, effectively defining its geometry in terms of a characteristic size W_j (here taken as the ribbon width) and location $\mathbf{r}_j = (\mathbf{R}_j, z_j)$ (e.g., the center of mass). Combining eqn (1) and (4), the potential in structure j is found to satisfy the self-consistent relation

$$\Phi_j^{(1,1)} = \Phi_j^{\text{ext}} + \sum_{j'=1}^N \eta_{j'}^{(1)} \mathcal{V}_{jj'} \mathcal{D}_{j'} \Phi_{j'}^{(1,1)}, \quad (5)$$

where, adopting the formalism of ref. 43, we have introduced the integrals

$$\mathcal{V}_{jj'} g(\vec{\theta}) \equiv \int d^2 \vec{\theta}' \frac{W_j g(\vec{\theta}')}{|\mathbf{r}_j - \mathbf{r}_{j'} + W_j \vec{\theta} - W_{j'} \vec{\theta}'|}$$

and the differential operator $\mathcal{D}_j g(\vec{\theta}) \equiv \nabla_{\vec{\theta}} \cdot [\mathbf{f}_j(\vec{\theta}) \nabla_{\vec{\theta}} g(\vec{\theta})]$, while the dimensionless parameter $\eta_j^{(s)} = i\sigma_j^{(1,s)}/s\omega W_j$ contains all the frequency and material dependence entering the intrinsic conductivity. In effect, the Coulomb integral $\mathcal{V}_{jj'}$ yields the potential produced at $\mathbf{r} = (\mathbf{R}_j + W_j \vec{\theta}, z_j)$ in ribbon j by the charge at $\mathbf{r}' = (\mathbf{R}_{j'} + W_{j'} \vec{\theta}', z_{j'})$ in ribbon j' . The system of eqn (5) can then be solved by constructing a block matrix spanning discretized real space elements: indeed, defining the potential in each structure as $\vec{\Phi}^{(1,1)} = (\Phi_1^{(1,1)}, \Phi_2^{(1,1)}, \dots, \Phi_N^{(1,1)})^T$ (similarly for $\vec{\Phi}^{\text{ext}}$), the self-consistent solution for the combined system is

$$\vec{\Phi}^{(1,1)} = (1 - \mathcal{M})^{-1} \vec{\Phi}^{\text{ext}}, \quad (6)$$

where \mathcal{M} is a square block matrix comprised of matrices $\mathcal{M}_{jj'} = \eta_{j'}^{(1)} \mathcal{V}_{jj'} \mathcal{D}_{j'}$, here defined by representing the operators $\mathcal{V}_{jj'}$ and $\mathcal{D}_{j'}$ on a real space grid, while 1 denotes the identity matrix. In the ESI† we provide details on the spatial representation of the operators $\mathcal{V}_{jj'}$ and $\mathcal{D}_{j'}$ leading to the block matrix equation of eqn (6) for nanoribbons.

The nonlinear response is conveniently described in terms of the induced charge density by using the continuity equation to recast eqn (3) as

$$\rho_j^{(n,s)}(\mathbf{R}) = \rho_{j,\text{NL}}^{(n,s)}(\mathbf{R}) + \frac{i}{s\omega} \nabla_{\mathbf{R}} \cdot \mathbf{f}_j(\mathbf{R}) \sigma_j^{(1,s)} \nabla_{\mathbf{R}} \times \sum_{j'=1}^N \int d^2 \mathbf{R}' \frac{\rho_{j'}^{(n,s)}(\mathbf{R}')}{\sqrt{|\mathbf{R} - \mathbf{R}'|^2 + (z_j - z_{j'})^2}}, \quad (7)$$

where $\rho_{j,\text{NL}}^{(n,s)} = -(i/s\omega) \nabla_{\mathbf{R}} \cdot \mathbf{j}_{j,\text{NL}}^{(n,s)}$ acts as a nonlinear source term analogous to Φ^{ext} in eqn (1). Then, adopting the formalism leading to eqn (5) and (6), the integro-differential equation above can be expressed as

$$\rho_j^{(n,s)} = \rho_{j,\text{NL}}^{(n,s)} + \eta_j^{(s)} \mathcal{D}_j \sum_{j'=1}^N \frac{W_{j'}}{W_j} \mathcal{V}_{jj'} \rho_{j'}^{(n,s)}. \quad (8)$$

Defining vectors $\vec{\rho}^{(n,s)} = (\rho_1^{(n,s)}, \rho_2^{(n,s)}, \dots, \rho_N^{(n,s)})^T$, the solution of eqn (8) can also be expressed in block-matrix form as

$$\vec{\rho}^{(n,s)} = (1 - \mathcal{N}^{(s)})^{-1} \vec{\rho}_{\text{NL}}^{(n,s)}, \quad (9)$$

where the elements $\mathcal{N}_{jj'}^{(s)} = W_j W_{j'}^{-1} \eta_{j'}^{(s)} \mathcal{D}_{j'} \mathcal{V}_{jj'}$ may be constructed by representing the operators $\mathcal{V}_{jj'}$ and $\mathcal{D}_{j'}$ as matrices spanning

discrete real-space elements in the 2D structures j and j' . In the ESI† we provide further details on the derivation of eqn (9) for the specific case of ribbons with translational symmetry in one dimension, which leads to a dependence of $\mathcal{V}_{jj'}$ and $\mathcal{D}_{j'}$ on the harmonic index s . In analogy to $\vec{\Phi}^{\text{ext}}$ in eqn (6), the vector $\vec{\rho}_{\text{NL}}^{(n,s)}$ in eqn (9) acts as the external source of nonlinear response in the system, and depends on the specific definition of the nonlinear current $\mathbf{j}_{\text{NL}}^{(n,s)}$.

2.2 Nonlinear response of graphene

In graphene doped to a Fermi energy E_F , the dominant contribution to the optical response at frequencies $\hbar\omega \lesssim E_F$ stems from intraband charge carrier motion, which can be described in the Boltzmann transport equation formalism by adopting the linearized electronic dispersion $\hbar\epsilon_{\mathbf{k}} = \pm \hbar v_F |\mathbf{k}|$ for electron (upper sign) and hole (lower sign) doping, where $v_F \approx c/300$ is the Fermi velocity in graphene. Following the prescription and methods of ref. 44, we express the current associated with the optical response at perturbation order n and harmonic index s in extended graphene as

$$\mathbf{j}_{\text{NL}}^{(n,s)} = \sigma^{(1,s)} \mathbf{E}^{(n,s)} + \mathbf{j}_{\text{NL}}^{(n,s)}, \quad (10)$$

where the first term accounts for the response of graphene to the induced field $\mathbf{E}^{(n,s)}$ mediated by the linear conductivity $\sigma^{(1,s)} = (ie^2 E_F / \pi \hbar^2) D_{s\omega}$, where $D_{s\omega} \equiv (s\omega + i\gamma)^{-1}$ is a complex frequency factor that includes inelastic scattering processes in the phenomenological rate γ introduced in the relaxation-time approximation, while the second term in eqn (10) accounts for nonlinear optical processes. In obtaining specific expressions for $\mathbf{j}_{\text{NL}}^{(n,s)}$, nonlocal effects in the optical response are incorporated by retaining terms up to linear order in the gradient of the electric field. For second-harmonic generation (SHG), we recover the result of ref. 44,

$$\mathbf{j}_{\text{NL}}^{(2,2)} = \sigma_A^{(2,2)} \mathbf{E}^{(1,1)} (\nabla_{\mathbf{R}} \cdot \mathbf{E}^{(1,1)}) + \sigma_B^{(2,2)} (\mathbf{E}^{(1,1)} \cdot \nabla_{\mathbf{R}}) \mathbf{E}^{(1,1)} + \sigma_C^{(2,2)} \nabla_{\mathbf{R}} (\mathbf{E}^{(1,1)} \cdot \mathbf{E}^{(1,1)}), \quad (11)$$

where

$$\sigma_A^{(2,2)} = \mp S^{(2)} D_{2\omega} D_{\omega} (3D_{\omega} + 4D_{2\omega}), \quad (12a)$$

$$\sigma_B^{(2,2)} = \mp S^{(2)} D_{2\omega} D_{\omega} \left(-D_{\omega} + 4D_{2\omega} - \frac{4}{\omega} \right), \quad (12b)$$

$$\sigma_C^{(2,2)} = \mp S^{(2)} D_{2\omega} D_{\omega} \left(-\frac{D_{\omega}}{2} - 2D_{2\omega} + \frac{2}{\omega} \right), \quad (12c)$$

with the prefactor $S^{(2)} \equiv ie^3 v_F^2 / 4\pi \hbar^2$. The current obtained in eqn (11) reflects the centrosymmetry of the honeycomb lattice in graphene, so that an even-ordered nonlinear response emerges only from gradients in the local electric field.^{29,45,46} Retaining electric field gradients in the third-order optical response, we obtain the third-harmonic generation (THG) current

$$\mathbf{j}_{\text{NL}}^{(3,3)} = \sigma^{(3,3)} \mathbf{E}^{(1,1)} (\mathbf{E}^{(1,1)} \cdot \mathbf{E}^{(1,1)}) + \mathbf{j}_{\text{NL}}^{(2,\{1,2\})}, \quad (13)$$

where $\sigma^{(3,3)} = (3ie^4 v_F^2 / 4\pi\hbar^2 E_F) D_{3\omega} D_{2\omega} D_{\omega}$ is the local third-order THG conductivity and the term $\mathbf{j}_{\text{NL}}^{(2,\{1,2\})}$ describes the cascaded contribution to the nonlinear optical response that arises from the second-order mixing of the linear field with the nonlinear field generated by the current of eqn (11) at the second harmonic.⁴⁷ As we show in the ESI,† the cascaded contribution to THG is tantamount to sum/difference frequency generation described by the nonlinear current

$$\begin{aligned} \mathbf{j}_{\text{NL}}^{(2,\{1,2\})} = & \sigma_{\text{A}}^{(2,1,2)} \mathbf{E}^{(1,1)} (\nabla_{\mathbf{R}} \cdot \mathbf{E}^{(2,2)}) + \sigma_{\text{A}}^{(2,2,1)} \mathbf{E}^{(2,2)} (\nabla_{\mathbf{R}} \cdot \mathbf{E}^{(1,1)}) \\ & + \sigma_{\text{B}}^{(2,1,2)} (\mathbf{E}^{(1,1)} \cdot \nabla_{\mathbf{R}}) \mathbf{E}^{(2,2)} + \sigma_{\text{B}}^{(2,2,1)} (\mathbf{E}^{(2,2)} \cdot \nabla_{\mathbf{R}}) \mathbf{E}^{(1,1)} \\ & + \sigma_{\text{C}}^{(2,1,2)} \sum_{j=x,y} E_j^{(1,1)} \nabla_{\mathbf{R}} E_j^{(2,2)} + \sigma_{\text{C}}^{(2,2,1)} \sum_{j=x,y} E_j^{(2,2)} \nabla_{\mathbf{R}} E_j^{(1,1)} \\ & + \sigma_{\text{D}}^{(2,1,2)} \nabla_{\mathbf{R}} (\mathbf{E}^{(1,1)} \cdot \mathbf{E}^{(2,2)}), \end{aligned} \quad (14)$$

where

$$\sigma_{\text{A}}^{(2,s_1,s_2)} = \mp S^{(2)} D_{(s_1+s_2)\omega} \times [3D_{s_2\omega}^2 + 2D_{(s_1+s_2)\omega} (D_{s_1\omega} + D_{s_2\omega})], \quad (15a)$$

$$\sigma_{\text{B}}^{(2,s_1,s_2)} = \mp S^{(2)} D_{(s_1+s_2)\omega} \left[-\frac{4D_{s_1\omega}}{s_2\omega} - D_{s_2\omega}^2 + 2D_{(s_1+s_2)\omega} (D_{s_1\omega} + D_{s_2\omega}) \right], \quad (15b)$$

$$\sigma_{\text{C}}^{(2,s_1,s_2)} = \mp S^{(2)} D_{(s_1+s_2)\omega} \left(\frac{4D_{s_1\omega}}{s_2\omega} - D_{s_2\omega}^2 \right), \quad (15c)$$

$$\sigma_{\text{D}}^{(2,s_1,s_2)} = \pm 2S^{(2)} D_{(s_1+s_2)\omega}^2 (D_{s_1\omega} + D_{s_2\omega}). \quad (15d)$$

The cascaded contribution to THG thus involves electric field gradients of both the fundamental and SHG fields produced in graphene. The nonlinear conductivities of graphene derived above incorporate nonlocal effects by including terms up to linear order in the electric field gradient, for which even-ordered nonlinear optical phenomena emerge in a centrosymmetric material. While this approximation is valid for optical wave vectors $\lesssim 1 \text{ nm}^{-1}$, higher-order corrections may become relevant for extremely-confined fields that vary dramatically on sub-nanometer length scales.^{37,39} In general, the perturbative formalism described here is compatible with optical pulses of moderate intensity employed in nonlinear optical experiments,^{27,28} while pulses of fluence $\gtrsim 1 \text{ J m}^{-2}$ are expected to produce transient effects associated with the induced out-of-equilibrium electronic distribution.^{33,48,49}

3 Results and discussion

We focus on the optical response of interacting highly-doped graphene nanoribbons, all of which have finite widths in \hat{x} and are translationally invariant in \hat{y} , so that the potential can be decomposed in plane waves indexed by a wave vector q according to $\Phi^{(n,s)}(\mathbf{R}) = \varphi^{(n,s)}(x) e^{isqy}$. The symmetry of such nanoribbon ensembles in \hat{y} simplifies our calculations for normally-impinging plane-wave illumination with electric field

amplitude E^{ext} polarized along \hat{x} , such that $\Phi^{\text{ext}} = -xE^{\text{ext}}$, and localized plasmon resonances can be optically excited in each ribbon. The nonlinear optical response is quantified by computing the induced charge density in eqn (9), from which the induced dipole moment (per unit length along \hat{y}) of the combined system $p_x^{(n,s)} = \sum_j \int dx x \rho_j^{(n,s)}$ yields the effective polariz-

ability per unit length $\alpha^{(n,s)} \equiv p_x^{(n,s)} / (E^{\text{ext}})^n$ and the susceptibility $\chi^{(n,s)} \equiv \alpha^{(n,s)} / (d_{\text{gr}} \sum_j W_j)$, where $d_{\text{gr}} = 0.33 \text{ nm}$ is the inter-layer spacing of graphite, commonly used to estimate the thickness of graphene.²⁵

The archetypical system in which to explore the nonlinear optical response associated with interacting localized 2D plasmons is a pair ($N = 2$) of co-planar ($z_1 = z_2$) graphene nanoribbons separated by a distance d , as illustrated schematically in Fig. 1a, where the ribbons have independent widths (W_1 and W_2), Fermi energies ($E_{\text{F}1}$ and $E_{\text{F}2}$), and damping rates (γ_1 and γ_2) that lead to distinct plasmon resonances ($\omega_{\text{p}1}$ and $\omega_{\text{p}2}$). For an isolated structure ($j = j'$) of size W_j and Fermi energy $E_{\text{F}j}$, the self-consistent relation for the scalar potential in eqn (5) reduces to the eigenvalue problem $\eta_m \mathcal{V}_{jj} \mathcal{D}_j \Phi^{(1,1)} = \Phi^{(1,1)}$, from which the eigenvalues η_m determine the plasmon resonances

$$\hbar\omega_m = \sqrt{\frac{-e^2 E_{\text{F}j}}{\pi l_m W_j}} \quad (16)$$

in the Drude conductivity model for graphene (neglecting losses). Following the prescription in the ESI,† the first three finite eigenvalues are computed as $\eta_1 = -0.0689$, $\eta_2 = -0.0289$, and $\eta_3 = -0.0184$. The plasmon resonance condition of eqn (16) sets the properties of graphene nanoribbon dimers that can simultaneously support plasmons at fundamental and harmonic frequencies of the incoming field, a configuration that we explore in Fig. 1b for ribbons with widths $W_1 = 160 \text{ nm}$ and $W_2 = 40 \text{ nm}$ at a common doping level $E_{\text{F}1} = E_{\text{F}2} = 0.4 \text{ eV}$, where both the linear optical response (here quantified by the absorption cross section) and SHG susceptibility (in logarithmic scale) are presented for several values of the co-planar ribbon separation d . Importantly, besides the enhancement of SHG provided by matching the lowest-order dipolar plasmon modes at both input and output frequencies, the dimer configuration provides the symmetry-breaking required to induce a nonvanishing dipolar second-order response. The influence of nonlocal effects is clearly enhanced by bringing the ribbons closer together, such that the dipolar SHG response intensifies with the stronger field gradients produced by near field coupling.

In an alternative approach to triggering SHG, we explore in Fig. 1c the response of a co-planar graphene nanoribbon dimer formed by ribbons with a common width $W_1 = W_2 = 100 \text{ nm}$ but unequal doping levels $E_{\text{F}1} = 0.2 \text{ eV}$ and $E_{\text{F}2} = 0.8 \text{ eV}$. Interestingly, although $W_1 + W_2$ is preserved in the spectra of panels (b) and (c), roughly one order of magnitude improvement in the SHG yield manifests in the latter case within the

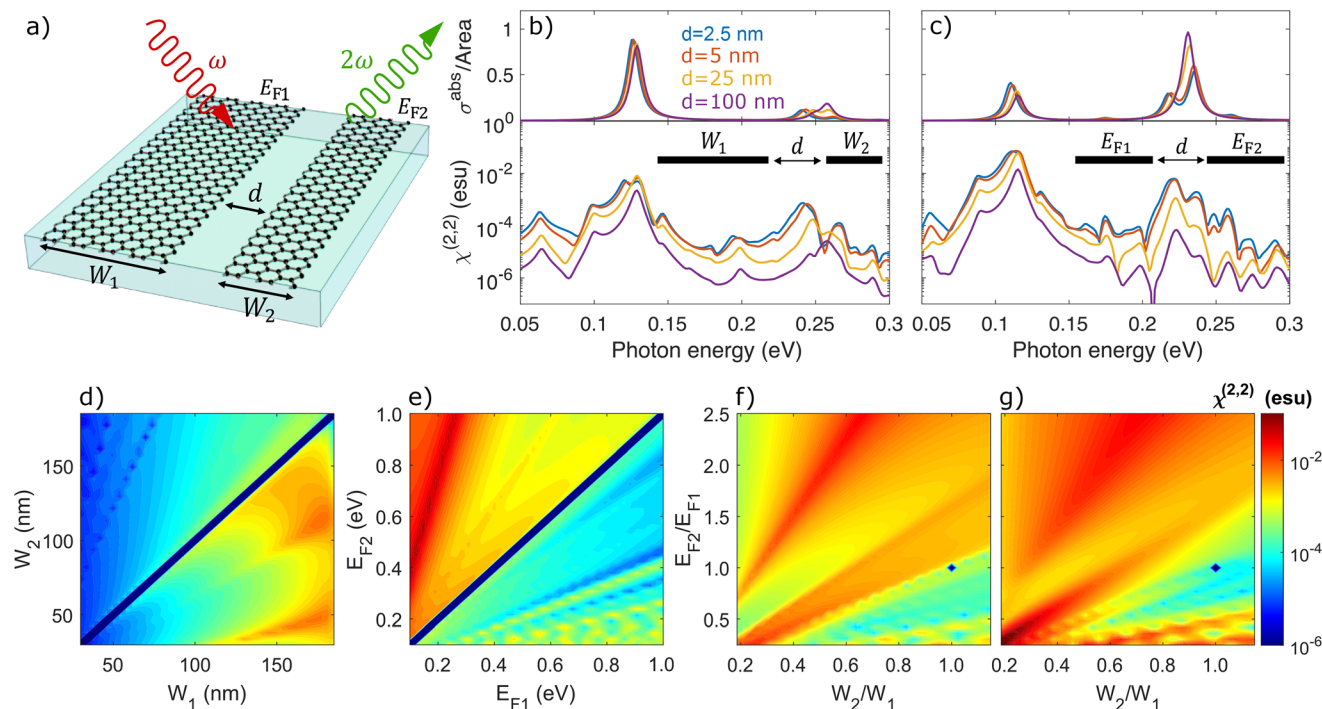


Fig. 1 Second-harmonic generation in co-planar asymmetric nanoribbon pairs. (a) Schematic illustration of second-harmonic generation (SHG) in two co-planar graphene nanoribbons separated by a distance d and characterized by widths W_j , Fermi energies E_{Fj} , and damping rates γ_j for $j \in \{1, 2\}$. (b) The effect of inter-ribbon interaction is explored in both the linear absorption cross section (upper panel) and the SHG susceptibility (lower panel) by varying the separation distance d for a dimer formed by arranging ribbons of width $W_1 = 160$ nm and $W_2 = 40$ nm at the same doping $E_{Fj} = 0.4$ eV, such that the frequency of the lowest-order dipolar plasmon resonance in ribbon $j = 1$ is half of that in ribbon $j = 2$ (i.e., frequency $\propto W_j^{-1/2}$). (c) Similar to (b), but for ribbons with equal width $W_j = 100$ nm and different dopings $E_{F1} = 0.2$ eV and $E_{F2} = 0.8$ eV. (d–f) SHG from co-planar ribbons spaced $d = 25$ nm apart when: (d) the ribbons have the same doping $E_{F1} = E_{F2} = 0.4$ eV and varying widths W_j ; (e) the ribbons have equal widths $W_1 = W_2 = 100$ nm and varying doping levels E_{Fj} ; (f) both the width and doping of ribbon $j = 2$ are changed. (g) Similar to (f), but for a small ribbon separation $d = 2.5$ nm. In panels (d–g), the impinging light frequency is maintained at the lowest-order dipolar plasmon resonance frequency $\hbar\omega = (-e^2 E_{Fj} / \pi \eta_1 W_j)^{1/2}$. Results are obtained for an inelastic broadening $\hbar\gamma_1 = \hbar\gamma_2 = 10$ meV and a homogeneous environment with permittivity $\epsilon = 1$.

same excitation energy window, presumably due to the larger overall Drude weight for the ribbon supporting a plasmon resonance at the second harmonic frequency. We also note the increased spectral splitting in the high-energy dipolar plasmon resonance of the $j = 2$ ribbon in both scenarios, which is attributed to hybridization with a higher-order mode supported by the $j = 1$ ribbon.⁵⁰ More specifically, analysis of the resonance condition in eqn (16) reveals that the spectral splitting in Fig. 1c is a consequence of hybridization between the first- (η_1) and third-order (η_3) dipolar (bright) modes.

To identify optimal configurations for plasmon-enhanced SHG in co-planar ribbon dimers, we present the SHG response while (passively) sweeping over the ribbon widths W_j at fixed doping $E_{Fj} = 0.4$ eV in Fig. 1d and when (actively) varying the doping levels E_{Fj} of ribbons with fixed width $W_j = 100$ nm in Fig. 1e, such that in both cases the ribbons are separated by $d = 25$ nm and the impinging optical frequency is fixed to the plasmon resonance in the $j = 1$ ribbon (i.e., $\omega = \omega_{p1}$). The broad parameter sweep encompasses situations in which the symmetry of the ribbon dimer in the polarization direction quenches the dipolar SHG response while also probing the double-resonance condition (e.g., $\omega_{p2} = 2\omega_{p1}$) explored in

Fig. 1b and c. We furthermore consider configurations in which the light frequency is tuned to the plasmon resonance specified by the attributes of the $j = 1$ ribbon, while both the width and doping of the second ribbon are varied according to Fig. 1f and g for separation distances $d = 25$ nm and $d = 2.5$ nm, respectively, that modify the inter-ribbon interaction. Our findings reveal that the SHG response can be amplified when multiple plasmon modes of the nanoribbon are resonant at either the fundamental or second-harmonic frequency, while the nonlinear response can be altered by orders of magnitude with only small variations in the Fermi energy of only one ribbon in a heterostructure.

While co-planar ribbons provide the required symmetry-breaking to trigger strong SHG, the inter-ribbon coupling is localized at the ribbon edges. Vertical stacking thus presents an alternative configuration to interface nanoribbons over a larger cross-sectional area, as illustrated schematically in Fig. 2a. The optical response of a stacked nanoribbon pair is presented in Fig. 2b for ribbons of width $W_1 = 160$ nm and $W_2 = 40$ nm with equal doping $E_{F1} = E_{F2} = 0.4$ eV, so that the lowest-order dipolar plasmon resonances satisfy $\omega_{p2} = 2\omega_{p1}$ as in Fig. 1b. The linear absorption cross section reveals strong

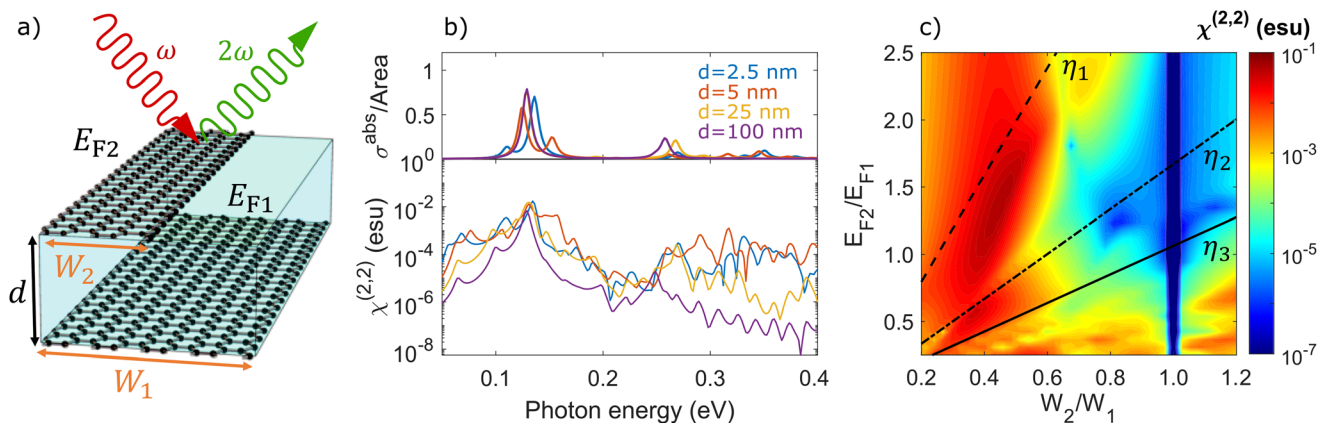


Fig. 2 Second-harmonic generation in stacked nanoribbon pairs. (a) Schematic of parallel graphene nanoribbons separated by a vertical distance d and aligned on one edge. Ribbon $j \in \{1, 2\}$ is characterized by a width W_j and Fermi energy E_{Fj} . (b) Linear absorption cross section (upper panel) and SHG susceptibility (lower panel) of a stacked nanoribbon pair with $W_1 = 160$ nm, $W_2 = 40$ nm, and $E_{F1} = E_{F2} = 0.4$ eV for different separation distances. (c) SHG susceptibility of a stacked ribbon pair separated by $d = 25$ nm when the illumination frequency is fixed to the lowest-order dipolar plasmon resonance of ribbon $j = 1$ with $W_1 = 160$ nm and $E_{F1} = 0.4$ eV as the width and doping of ribbon $j = 2$ are varied. Results are obtained for self-standing ribbons and a damping $\hbar\gamma_j = 10$ meV.

hybridization of the dipolar plasmon resonance as the ribbon separation parameter d decreases, while the SHG susceptibility $\chi^{(2,2)}$ presents peaks of similar magnitude as those obtained in the co-planar configuration that emerge at the plasmon resonances. We attribute this behaviour to the greater nanoribbon interaction area available in the stacked geometry, which ultimately leads to larger hybridization effects.

In Fig. 2c we maintain $W_1 = 160$ nm and $E_{F1} = 0.4$ eV in the first ribbon and fix the illumination frequency to the lowest-order dipolar plasmon resonance ($\hbar\omega_{p1} = 0.13$ eV) while varying the width and doping of ribbon $j = 2$ in order to explore the optimal second-harmonic response in the stacked configuration. Note that the dip in SHG response at $W_2 = W_1 = 160$ nm corresponds to an inversion-symmetric heterostructure, independent of the chosen Fermi energies. Prominent features in the SHG response correspond to overlap of the leading bright modes with the second harmonic frequency in ribbon $j = 2$. Consequently, although not radiating into the far field, the second-order ribbon eigenmode may still contribute significantly to the SHG response. Analogously, the large SHG below $E_{F2} = 0.2$ eV in Fig. 2c originates in coalescing higher-order modes. In particular, when the illumination frequency matches the dipolar plasmon resonance of ribbon $j = 1$, an enhancement in harmonic generation at $s\omega$ emerges when the condition $E_{F2}/E_{F1} = s^2 W_2 \eta_m / W_1 \eta_1$ is met for eigenvalues η_m . We indicate the resonance conditions for the first three finite ribbon eigenmodes in Fig. 2c by black dashed, dot-dashed, and solid lines, which however do not match perfectly with maxima in the SHG response due to hybridization effects. Larger ribbon separations would limit mode hybridization, thus matching the optimal SHG response with the aforementioned condition, as illustrated in Fig. S2 in the ESI.† Furthermore, the optimal horizontal alignment in stacked ribbon dimers comprised of ribbons with constant width and different doping levels has been analyzed in Fig. S3

in the ESI,† and underscores the resonant enhancement of SHG that occurs when $\omega_{p2} = 2\omega_{p1}$.

Now, turning our attention to the third-order response, we investigate THG in a system formed by three interacting graphene ribbons with independent widths W_j and doping levels E_{Fj} for $j \in \{1, 2, 3\}$, separated by a common horizontal gap distance d , as depicted in Fig. 3a. In such a nanoribbon triad, each of the three ribbons may have a distinct plasmon resonance frequency ω_{pj} that we can tune actively or passively to realize a system sustaining plasmon resonances at the fundamental, second, and third harmonic frequencies of the impinging light. In Fig. 3b, we present the absorption cross section (upper panel) and THG susceptibility $\chi^{(3,3)}$ (lower panel) for ribbons of a fixed doping $E_{Fj} = 0.45$ eV and widths $W_1 = 220$ nm, $W_2 = 55$ nm, and $W_3 = 25$ nm at different horizontal separations d , which simultaneously satisfy the condition $\omega_{p2} = 2\omega_{p1}$ and $\omega_{p3} = 3\omega_{p1}$, where the solid curves show the results for three parallel ribbons and the black-dotted curves are calculated for a single ribbon with a width equal to the sum of the three ribbons. The same triple-resonance condition is obtained for ribbons of equal width $W_j = 100$ nm and Fermi energies $E_{F1} = 0.1$ eV, $E_{F2} = 0.4$ eV, and $E_{F3} = 0.9$ eV, a configuration that is shown in Fig. 3c to exhibit plasmon mode interference and stronger THG at lower frequencies. In particular, the splitting of the two high-energy modes in Fig. 3c is observed in the linear response, which arises due to mixing with the dark mode of both ribbon $j = 1$ and ribbon $j = 2$. Comparing Fig. 3b with Fig. 3c, we conclude that the configuration with constant width is superior to the configuration with constant doping by almost one order of magnitude, and we emphasize that the sum of the widths have been preserved on both cases. Furthermore, Fig. 3b indicates that a single ribbon with the combined width of the triad displays similar THG response at $\hbar\omega \approx 0.1$ eV, but is several orders of magnitude smaller at larger excitation energies.

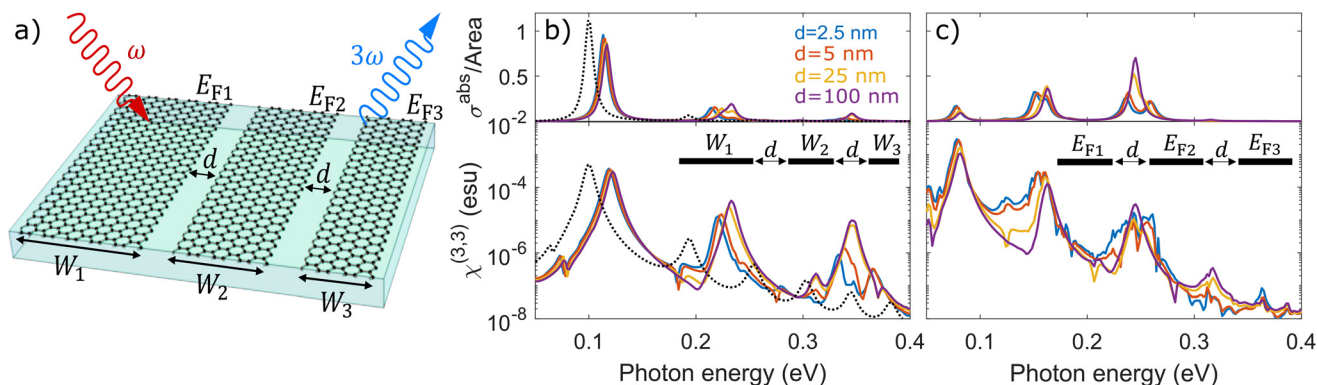


Fig. 3 Third-harmonic generation in a co-planar nanoribbon triad. (a) Schematic of co-planar graphene ribbons of width W_j and doping E_{Fj} for $j \in \{1, 2, 3\}$, separated by a common gap distance d . (b) Linear absorption cross section (upper panel) and THG response when ribbons of width $W_1 = 220$ nm, $W_2 = 55$ nm, and $W_3 = 25$ nm are equally-doped to $E_{Fj} = 0.45$ eV for different gap distances d . (c) Same as in (b), but for ribbons of equal width $W_j = 100$ nm and different doping levels $E_{F1} = 0.1$ eV, $E_{F2} = 0.4$ eV and $E_{F3} = 0.9$ eV. Results are obtained for self-standing ribbons and damping $\hbar\gamma_j = 10$ meV.

An alternative approach to a system suited to fulfill the triple-resonance condition is that of three graphene ribbons vertically separated by a distance d , as illustrated schematically in Fig. 4a. Neglecting hybridization effects, the triple-resonance condition is assured by choosing the same material parameters as for the previously considered co-planar THG system, from which we obtain the spectra shown in Fig. 4b (c) for constant doping level (width) and different widths (doping levels). In analogy to SHG from two vertically separated ribbons, the increased overlap of graphene material for the three stacked ribbons leads to more significant plasmon hybridization, as revealed in Fig. 4c by the blueshift of the lowest-order dipolar resonances with decreasing vertical separation distance d . Interestingly, for the equally-doped ribbon triad, only the THG signal associated with the dipolar

plasmon resonance of the middle ribbon changes substantially as the separation is reduced (see the lower panel of Fig. 4b), while all dipolar resonances in the THG response are modified for ribbons of equal width (see the lower panel of Fig. 4c). The latter situation is attributed to the decreasing oscillator strength of the plasmon resonance at lower energies as the ribbons are brought closer together, approaching the limit of a single ribbon with a net Drude weight $\sum_j E_{Fj}$.⁵¹ The dotted blue line in the lower panels of Fig. 4b and 4c show the optical response when the cascaded contribution is neglected for closely spaced ribbons with $d = 2.5$ nm, *i.e.*, setting $j_{NL}^{(2,1,2)} = 0$ in eqn (13). The cascaded effect seems to have the largest impact at high excitation energies in the system with constant doping, while the opposite trend is reported in the system with constant ribbon width.

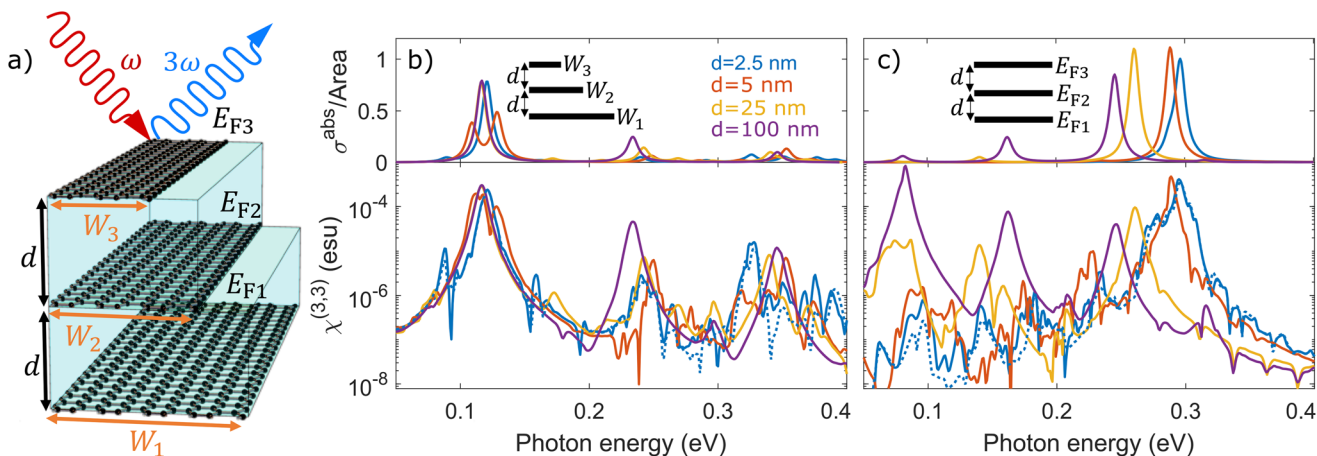


Fig. 4 Third-harmonic generation in stacked nanoribbon triads. (a) Schematic illustration of three stacked ribbons vertically separated by the same distance d and with independent widths W_j and dopings E_{Fj} for $j \in \{1, 2, 3\}$. (b) Linear and THG response of a stair-like configuration formed by combining ribbons of widths $W_1 = 220$ nm, $W_2 = 55$ nm, and $W_3 = 25$ nm at the same doping $E_{Fj} = 0.45$ eV. The left-most edges of the ribbons are vertically aligned. (c) Similar to (b) but for equal widths $W_j = 100$ nm and different doping levels $E_{F1} = 0.1$ eV, $E_{F2} = 0.4$ eV, and $E_{F3} = 0.9$ eV. Note that the nanoribbon parameters in both (b) and (c) are chosen to keep a constant total width $\sum_j W_j = 300$ nm and satisfy the triple-resonance condition $\omega_{p1} = \omega_{p2}/2 = \omega_{p3}/3$. The dotted curves indicate the same system as the solid curves (distinguishable only for $d = 2.5$ nm), but omitting nonlocal terms in the calculation. The phenomenological damping of graphene is set to $\hbar\gamma_j = 10$ meV and the dielectric environment is $\epsilon = 1$.

To further enhance the electric field gradients that give rise to even-ordered nonlinear optical effects, we may introduce additional asymmetry in graphene heterostructures by interfacial electron- and hole-doped nanoribbons. In particular, the nonlocal intraband SHG conductivity of graphene in eqn (11) and (14) exhibits a dependence on the sign of the Fermi energy, suggesting that the induced charge associated with SHG should exhibit additional dipolar character when ribbons of opposite doping interact. In Fig. 5 we consider a dimer comprised of staggered ribbons and compare the harmonic generation produced when the doping charge level is equal or opposite for various inter-ribbon separations. While the same linear response appears in Fig. 5a for electron and hole doping, a strong SHG signal emerges from the dimer of oppositely-doped ribbons in Fig. 5b, which vanishes in the dimer of equally-doped ribbons (not shown). The resulting THG yield for the equally-doped ribbons in Fig. 5c differs from that of the oppositely-doped dimer in Fig. 5d for the smallest separation distance considered due to a significant cascaded nonlinear response, particularly for photon energies near the lowest-order dipolar plasmon resonance of the individual ribbons that in this case are strongly hybridized.

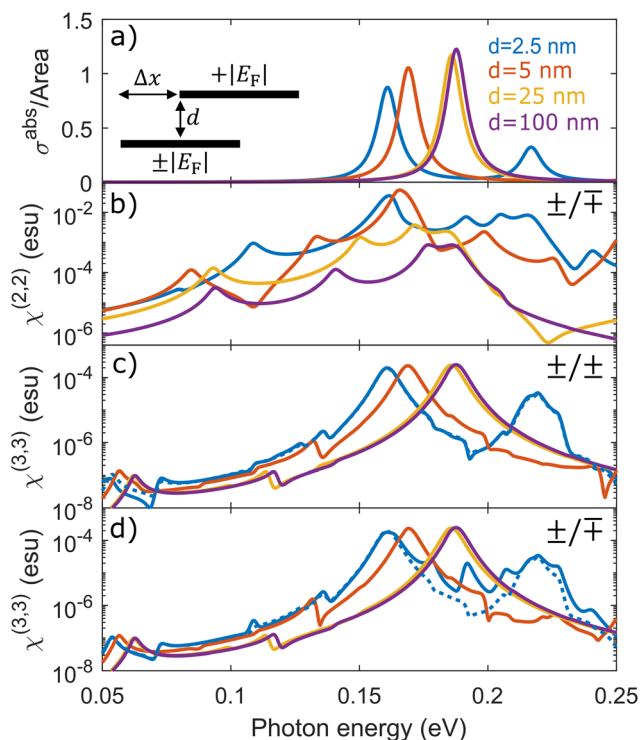


Fig. 5 Harmonic generation in equally- and oppositely-doped graphene nanoribbon dimers. (a) Linear optical response of staggered graphene nanoribbons with the same width $W = 100$ nm offset by $\Delta x = 50$ nm and separated vertically by a distance d . The response is independent of whether the ribbons are equally or oppositely doped to a Fermi level $|E_F| = 0.5$ eV. The corresponding SHG response (b) is nonvanishing only for oppositely-doped ribbons, while THG spectra appear in each case and are shown for equally-doped (c) and oppositely-doped (d) ribbons, including (solid curves) and omitting (dashed curves) the cascaded contribution. We choose $\hbar\gamma_{lj} = 10$ meV and $\epsilon = 1$ in all cases.

4 Conclusions

The strong intrinsic nonlinear optical response of graphene can be further enhanced by its highly-confined and electrically-tunable plasmon resonances, which are conveniently excited by far-field illumination in subwavelength structures. The semianalytical method we introduce here enables explorations over a wide parameter space to reveal optimal configurations for harmonic generation from interacting graphene nanostructures. We find the nonlinear efficiency to depend crucially on nonlocal effects in the optical response. While pristine graphene does not produce an even-ordered response due its centrosymmetric crystal structure, the breaking of symmetry in patterned morphologies is predicted here to produce intense SHG when the impinging light frequency ω matches one or more plasmon resonances (*i.e.*, when $\omega = \omega_{\text{ps}}/s$ for $s = 1$ and/or $s = 2$). Similar conclusions apply to THG, which is dominated by a local nonlinear response but can be sensitive to nonlocal effects through the cascaded second-order wave mixing of fundamental and second-harmonic frequency components in the near field. In practice, the heterostructures under consideration could be fabricated by inserting passive dielectric spacers such as hexagonal boron nitride with a prescribed number of atomic layers to define the vertical spacing. In addition, each graphene plane could be lithographically patterned to achieve the desired lateral spacing. Our findings underscore the importance of nonlinear near-field interactions and their relatively untapped potential to develop efficient nano-optical devices, along with the appeal of graphene as an actively-tunable plasmonic material in subwavelength heterostructures to independently tune different optical resonators and control nonlinear optical phenomena.

Conflicts of interest

There are no conflicts to declare.

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